

RF Power Amplifier

RF10162-1000 P

This solid state power amplifier is designed for reliable, trouble-free service. It operates in a class A during the pulse and includes RF protection circuits, cooling installations and a 230 V AC power supply. The amplifier is accommodated in a 19" system housing.

Features :

- * 1100 Watts saturated output power
- * 60 dB minimum gain
- * Electronic Attenuator external electricly controlled , dynamic range 15 dB min
- * Power indicator and status via **RS232 or IEEE488**
- * VSWR protection by power reduction
- * Temperature protection

Applications :

- * medical NMR

Specifications

Characteristics	Data	Units
Frequency range	10 - 162	MHz
RF output peak power		
Typ.	1050	W
Min	1000	W
Class	A during the pulse	
Power gain min	60	dB
Gain dynamique range	15	dB
Off-state power spectral density	-150	dBm/Hz
Max. input power	0	dBm
In / Out impedances nom.	50	Ohms
Input VSWR	1,5 : 1	
Load VSWR for rated output power	up to 1.8 : 1	
VSWR mismatch	infinite	
Protection circuits	Over temperature, short, open	
Harmonics typ.	-15	dBc
Gating signal	TTL	
Pulse width	1 to 20	mS
Duty cycle	10	%
Rise and fall time	< 500	µS
RF connector input	N female	
RF connector output	N female	
Cooling	Forced air	
Operating temperature Range	0 °C ... + 40	° C
Power Supply	235 AC +/- 10 % , 47-63 Hz	V
Dimensions (W x L x H)	6 U 19" Rack 490 x 460	mm
All data at room temperature + 22 °C, into 50 Ohms, subject to change without notice		

WWW.rfpa.com

Made in European Union

13/03/2002

R.F.P.A. S.A.

Parc d'activité de Fontaudin F33370 Artigues près Bordeaux
France Tél : +33 (0)5 56 86 85 84 Fax: + 33 (0) 5 56 86 55 56